

SLWS173B-APRIL 2005-REVISED SEPTEMBER 2006

# 2.5-GHz Integrated Up-Converter

### **FEATURES**

- Performs Up-Conversion in 2.5-GHz Radios MDS/MMDS/WCS
- Integrated IF Amplifier, Mixer and LO Buffer Amplifier
- Provision for External Image Reject / Band-Pass Filter
- TTL Switched Attenuator For Gain Control
- TTL Controlled Amplifier Power Down
- RF Frequency Range: 2100 2700 MHz
- 20 dB of Gain with 16-dB Switched Attenuator
- Output P-1 dB: +14 dBm, Typical
- Output IP3: +24 dBm, Typical
- LO Drive Level = 0 dBm, Typical

### **DESCRIPTION**

The TRF1122 up-converts a UHF IF signal to an RF signal in the 2100-MHz to 2700-MHz range for 2.5-GHz radio applications. The TRF1122 has 20 dB of gain and an output P-1 dB of +14 dBm, typical. A TTL compatible, 1-bit 16-dB switched attenuator is provided for gain control and the IF and RF amplifiers can be shut off via a TTL control signal for power critical or TDD applications. In order to provide system requirements for LO/spurious rejection, the TRF1122 offers a signal path to an off-chip band-pass filter. Specifications are provided assuming an in-band 2-dB insertion loss filter.

The TRF1122 is designed to complete the second up-conversion in Texas Instruments complete 2.5-GHz chip set. The linear nature of the up-converter makes it ideal for complex modulations schemes such as high order QAM or OFDM.

#### **DEVICE INFORMATION** TRF1122 (TOP VIEW) GND GND RFI 31 30 29 28 27 26 25 IADJ **MXRADJ** VDD2 **UCEN** 23 GND **MXRO** 22 **UCATTN GND GND IFIN RFO** 19 **IFIP** LOADJ1 **VDDIFP** VNEG **VDDIFN** 11 12 13 14 15 16

Figure 1. TRF1122 Pin Out

VDDLO

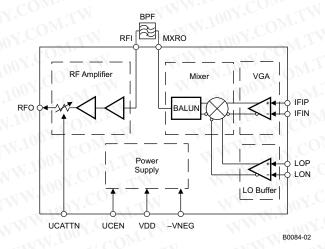


Figure 2. Functional Block Diagram



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#### ABSOLUTE MAXIMUM RATINGS

		VALUE	UN
VDD	Positive DC Supply Voltage, VDD	0.0 to +5.50	V
-VDD	Negative DC Supply Voltage, -VDD	-5.5 to 0	V
Pin	RF Input Power	10.1	dBn
TJ	Junction Temperature	200	°C
Pd	Power Dissipation	MAN M. TON COL	W
	Digital Input Pins	-0.3 to 5.5	V
$\theta_{\sf JC}$	Thermal Resistance Junction to Case <sup>(1)</sup>	9.01	°C/V
T <sub>stg</sub>	Storage Temperature	-40 to 105	°C
T <sub>op</sub>	Operating Temperature	-40 to 85	°C
D. J.	Lead Temperature	260	°C

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#### DC SPECIFICATIONS

V mA V mA mA
V mA
mA
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<sup>(1)</sup> Thermal resistance is junction to ambient assuming thermal pad with 16 thermal vias under package metal base. See Recommended WWW.100Y.C PCB layout.



## **ELECTRICAL CHARACTERISTICS**(1)

Unless otherwise stated VDD = 5.0 V, VNEG = -5 V, External Filter loss = 2 dB,  $T_{\Delta}$  = 25°C

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
IF	IF input frequency	COM.	- 1	325		MHz
F <sub>RF</sub>	RF output frequency	M. 100 F. COM.	2100		2700	MHz
G T	Gain	UCATTN = TTL High, Input IF Impedance is 100 Ω differential	20			dB
- 11	Switched attenuator range	Valid at 2.5 GHz	15	16	17	dB
G <sub>NB</sub>	Gain flatness / 6 MHz	MAN TOOK OF	WILL		0.2	dB
OP-1dB	Output power at 1 dB compression, high gain	UCATTN = TTL High	TV	14		dBm
OIP3	Output third order intercept point, high gain	UCATTN = TTL High	Mi	24		dBm
N.Co.	Gain: IF to MXRO	UCATTN = TTL High	TIMO	1		dB
N.CC	Gain: RFI to RFO	UCATTN = TTL High	70-11	19		dB
Z <sub>RF</sub>	RF output impedance	Differential	$CO_{Mr}$	50		Ω
RL <sub>RF</sub>	RF output: return loss	$Z = 50 \Omega$ , $P_{LO} = 3 dBm$ , $F_{RF} = 2100-2700 MHz$	.COM	-10	Ī	dB
Z <sub>LO</sub>	LO input impedance	Differential	'V'CO	100	N	Ω
P <sub>LO</sub>	LO input power	Referenced to 100 $\Omega$ differential	-3	0	3	dB
RL <sub>LO</sub>	LO input return loss	Referenced to 100 $\Omega$ differential, LO input = 3 dBm	OY.C	-10	LA.	dB
Z <sub>IE</sub>	IF input impedance	Differential	100 -	100	- T	Ω
RL <sub>IF</sub>	IF1 input return loss	Referenced to 100 Ω differential	100 X	-10	T.I.A	dB
- TIN .	LO to RFO: leakage <sup>(1)</sup>	LO input = 0 dBm		-20	- 177	dBm

<sup>,</sup> sut. WWW.100Y.COM.TW (1) Performance is sensitive to impedance termination and board layout. WWW.100Y.CO WWW.100Y.COM.TW

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#### **TERMINAL FUNCTIONS**

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TERM	/INAL	NO.	TYPE	DESCRIPTION
NO.	NAME	1/0	TYPE	DESCRIPTION
1	IADJ	NW.Y	MY.C	Not connected for normal operation. Amplifier Bias Adjustment. Do not ground this pin or connect to any other pin.
2	VDD2	WW.	Power	RF amplifier bias +5 V
3, 5, 9, 11, 15, 16, 21, 28–30, 32	GND	NWW	100X	Ground
4	UCATTN	MM	Digital	Logic high is high gain, Logic low reduces gain by 16 dB. Normally set high.
6	RFO	0	Analog	RF output from RF amplifier
V.(7)M.	LOADJ1	W	NW.IO	Not connected for normal operation. LO common gate bias adjustment. Do not ground this pin or connect to any other pin.
8 CO	VNEG	1	Power	Negative bias used for enable circuitry -5 V. This pin can be grounded if the user does not use the UCEN pin to turnoff the amplifier. If the VNEG is grounded the UCEN pin should be tied high.
10	LOADJ2		WWW	Not connected for normal operation. LO amplifier bias adjustment. Do not ground this pin o connect to any other pin.
12	LOP	I	Analog	LO input, Positive, Internally ac coupled
13	LON	et I	Analog	LO input, Negative, Internally ac coupled.
14	VDDLO	1	Power	Positive power for LO amplifier, +5 V.
17	VDDIFN	WI	Analog	VDD supply for IF amplifier, negative, +5 V
18	VDDIFP		Analog	VDD supply for IF amplifier, positive, +5 V
19	IFIP	T. I	Analog	IF input, positive, dc coupled, Typical dc voltage is 1.2 V.
20	IFIN		Analog	IF input, negative, dc coupled Typical dc voltage is 1.2 V.
22	MXRO	0	Analog	Output of mixer (after balun) 50 $\Omega$ impedance with high impedance DC ground.
23	UCEN	NT.	Digital	Set HIGH to enable IF amplifier and RF amplifiers
24	MXRADJ	11.	Analog	Normally grounded. Provide 0 $\Omega$ jumper to ground.
25	IFADJ	OM		Not connected for normal operation. IF amplifier bias adjustment. Do not ground this pin or connect to any other pin.
26	VDDIF	dM	Power	Positive supply for IF bias circuitry +5 V
27	RFL	L	Analog	Input to RF amplifier, 50 $\Omega$ impedance, Internally AC coupled
31	VDDI	CO	Power	RF amplifier bias +5 V
Back	GND	ST CC	MI	Back of package has metal base that must be grounded for thermal and RF performance.

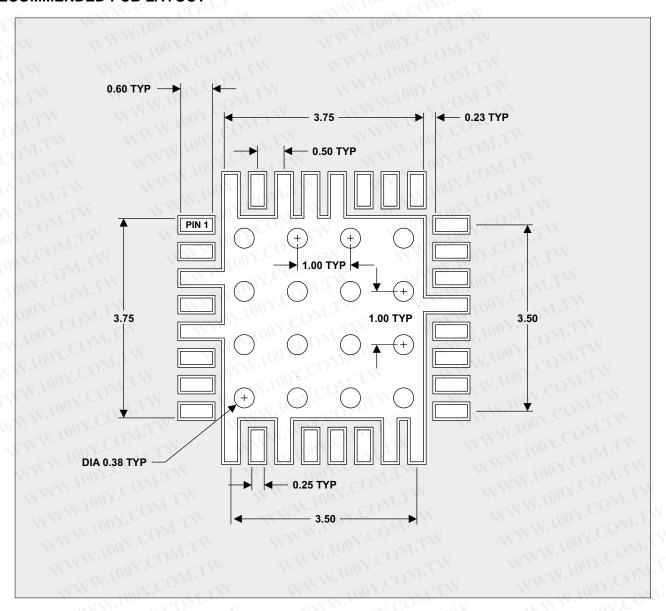
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## RECOMMENDED PCB LAYOUT



Solder Mask. No Solder Mask Under Chip, On Lead Pads or On Ground Connections.

Notes: 9 Via Holes, Each 0.38 mm. DIMENSIONS in mm

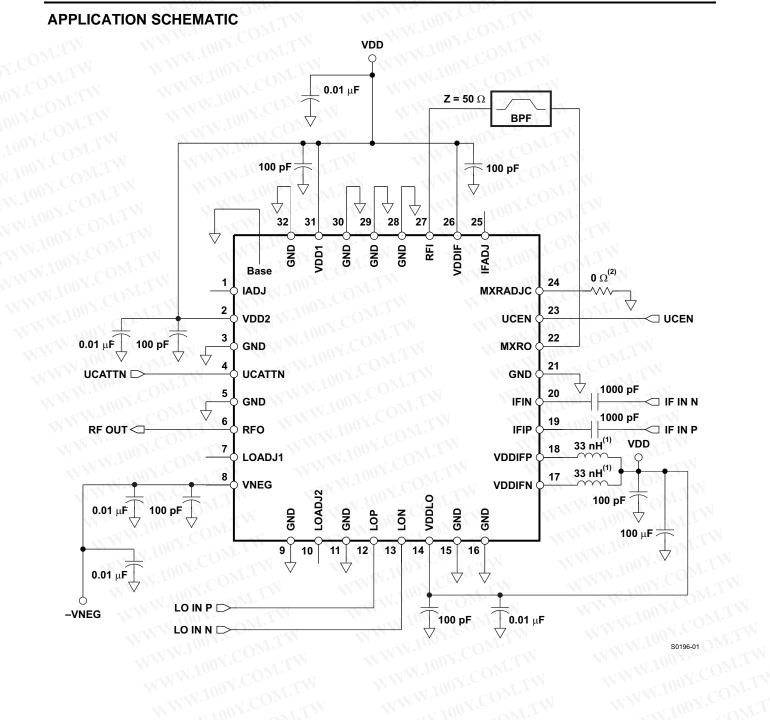
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A. Four layer Board, Starting material: two: 10 mil core FR4 with 1 oz copper, both sides, pressed with 8 mil thick prepreg. Via plating ½ oz copper plate, final plate White immersion tin. Final thickness: 0.033" to 0.037" thick.

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#### APPLICATION SCHEMATIC



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### APPLICATION INFORMATION

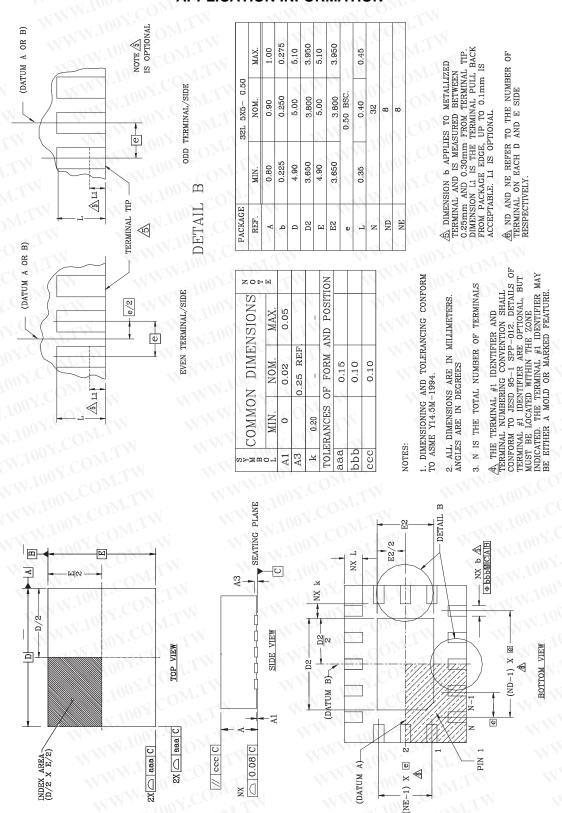


Figure 3. Package Outline: 5 mm x 5 mm LPCC 32-Pin Leadless Package





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### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings (4)	Samples
TRF1122IRTMR	ACTIVE	VQFN	RTM	32	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR		RF 122	Samples
TRF1122IRTMRG3	ACTIVE	VQFN	RTM	32	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR		RF 122	Samples
TRF1122IRTMT	ACTIVE	VQFN	RTM	32	250	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR		RF 122	Samples
TRF1122IRTMTG3	ACTIVE	VQFN	RTM	32	250	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR		RF 122	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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<sup>&</sup>lt;sup>(4)</sup> Only one of markings shown within the brackets will appear on the physical device.



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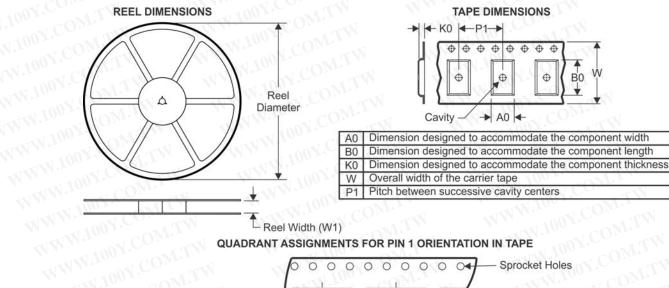
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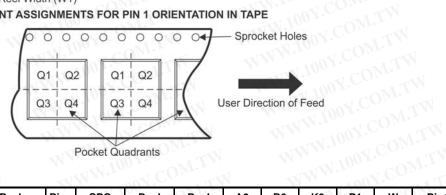
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## TAPE AND REEL INFORMATION



### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TRF1122IRTMR	VQFN	RTM	32	2500	330.0	12.4	5.3	5.3	1.5	8.0	12.0	Q2
TRF1122IRTMT	VQFN	RTM	32	250	180.0	12.4	5.3	5.3	1.5	8.0	12.0	Q2
WWW.100	OV.CON	M.TW MT.MC	<b>S</b> Ī	W	MM.100	M.CO.	M.TV DM.T	V VV	W	MMA MMA	N.100	N.COM

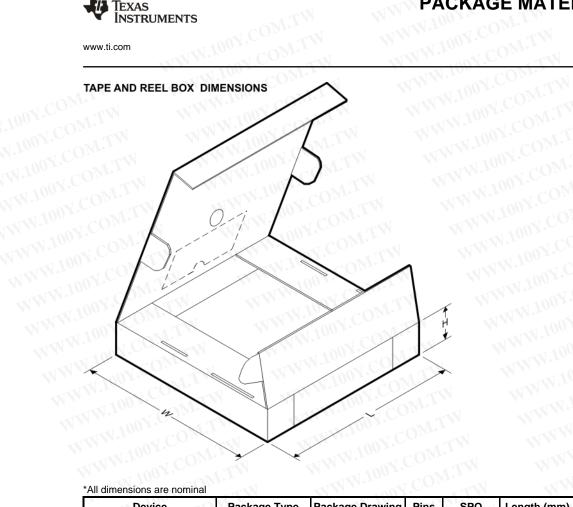
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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TRF1122IRTMR	VQFN	RTM	32	2500	338.1	338.1	20.6
TRF1122IRTMT	VQFN	RTM	32	250	210.0	185.0	35.0

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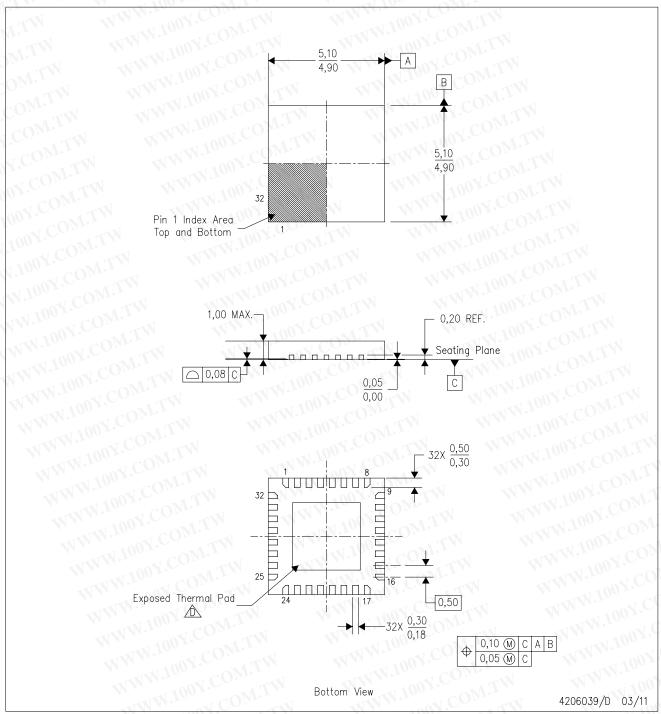
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# RTM (S-PVQFN-N32)

# PLASTIC QUAD FLATPACK NO-LEAD



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- Ç. QFN (Quad Flatpack No-Lead) Package configuration.
- The Package thermal pad must be soldered to the board for thermal and mechanical performance.

  See product data sheet for details regarding the exposed thermal pad dimensions.
- E. Package complies to JEDEC MO-220.



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